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# DS26LV31QML 3V Enhanced CMOS Quad Differential Line Driver

Check for Samples: DS26LV31QML

## FEATURES

- Comparable to Both TIA/EIA-422 and ITU-T V.11 Standards.
- Interoperable with Existing 5V RS-422
  Networks
- Low Quiescent Current
- Pin Compatible with DS26C31

## DESCRIPTION

The DS26IV31 is a high-speed quad differential CMOS driver that is comparable to the TIA/EIA-422-B and ITU-T V.11 standards. The CMOS DS26LV31 features low static I<sub>CC</sub> of 125  $\mu$ A Max which makes it ideal for battery powered and power conscious applications. Differential outputs have the same V<sub>OD</sub> specification (≥2V) as the 5V version. The EN and EN inputs allow active Low or active High control of the TRI-STATE outputs. The enables are common to all four drivers. Protection diodes protect all the driver inputs against electrostatic discharge. The driver and enable inputs (DI, EN, EN) are compatible with low voltage LVTTL and LVCMOS devices.

### **Connection Diagram**

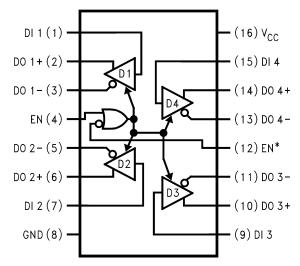


Figure 1. CLGA Package- Top View See Package Number NAD0016A

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# DS26LV31QML

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TEXAS INSTRUMENTS

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### Absolute Maximum Ratings (1)(2)

Supply Voltage (V <sub>CC</sub> )	-0.5V to 7.0V
DC Input Voltage (VI)	-0.5V to V <sub>CC</sub> +0.5V
DC Output Voltage (V <sub>O</sub> ) Power off	-0.5V to 7V
Clamp Diode Current (I <sub>IK</sub> , I <sub>OK</sub> )	±20mA
DC Output Current, per Pin (I <sub>O</sub> )	±150mA
Storage Temperature Range (T <sub>Stg</sub> )	-65°C ≤ T <sub>A</sub> ≤ +150°C
Lead Temperature (T <sub>L</sub> ) Soldering, 4 seconds	260°C
Maximum Power Dissipation +25°C (3)	1119mW
Thermal Resistance	
θ <sub>JA</sub>	134°C/W
θ <sub>JC</sub>	12.5°C/W

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not verify specific performance limits. For verified specifications and test conditions, see the Electrical Characteristics. The verified specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

(2) Unless otherwise specified, all voltages are referenced to ground. All currents into device pins are positive, all currents out of device pins are negative.

(3) Derate W package 7.5mW/°C above +25°C.

### **Recommended Operating Conditions**

Supply Voltage (v <sub>CC</sub> )	3.0V to 3.6V
DC input or Output Voltage (VI, VO)	0V to V <sub>CC</sub>
Operating Temperature Range (T <sub>A</sub> )	-55°C ≤ T <sub>A</sub> ≤ +125°C

#### Table 1. Quality Conformance Inspection Mil-Std-883, Method 5005 - Group A

Subgroup	Description	Temp °C
1	Static tests at	25
2	Static tests at	125
3	Static tests at	-55
4	Dynamic tests at	25
5	Dynamic tests at	125
6	Dynamic tests at	-55
7	Functional tests at	25
8A	Functional tests at	125
8B	Functional tests at	-55
9	Switching tests at	25
10	Switching tests at	125
11	Switching tests at	-55
12	Settling time at	25
13	Settling time at	125
14	Settling time at	-55

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## DS26LV31M Electrical Characteristics DC Parameters

Parameter		Test Conditions	Notes	Min	Max	Units	Sub- groups	
V <sub>IH</sub>	Logical "1" Input Voltage		(1)	2.0		V	1, 2, 3	
V <sub>IL</sub>	Logical "0" Input Voltage		(1)		0.8	V	1, 2, 3	
V <sub>OD1</sub>	Differential Output Voltage	R <sub>L</sub> = No Load, V <sub>CC</sub> = 3.0/3.6V	(2)		4.0	V	1, 2, 3	
V <sub>OD2</sub>	Differential Output Voltage	$R_{L} = 100\Omega, V_{CC} = 3.0/3.6V$	(2)	2.0		V	1, 2, 3	
$V_{OD2}$ - $\overline{V}_{OD2}$	Difference in Differential Output	$R_L = 100\Omega, V_{CC} = 3.0/3.6V$	(2)	-0.4	0.4	V	1, 2, 3	
V <sub>OD3</sub>	Differential Output Voltage	$R_L = 3900\Omega, V_{CC} = 3.0/3.6V$	(2)		3.6	V	1, 2, 3	
V <sub>OC</sub>	Common Mode Output Voltage	$R_L = 100\Omega, V_{CC} = 3.0/3.6V$	(2)		2.0	V	1, 2, 3	
V <sub>OC</sub> -V <sub>OC</sub>	Difference in Common Mode Output	$R_L = 100\Omega, V_{CC} = 3.0/3.6V$	(2)	-0.4	0.4	V	1, 2, 3	
IIL	Low Level Input Current	$V_I = Gnd, V_{CC} = 3.6V$		-10		μA	1, 2, 3	
I <sub>IH</sub>	High Level Input Current	$V_{I} = V_{CC}, V_{CC} = 3.6V$			10	μA	1, 2, 3	
V <sub>CL</sub>	Input Clamp Voltage	I <sub>I</sub> = -18mA, V <sub>CC</sub> = 3.0V			-1.5	V	1, 2, 3	
I <sub>CC</sub>	Quiescent Power Supply Current	$\label{eq:local_local_states} \begin{array}{l} I_O = 0 u A, \ V_I = V_{CC} \ or \ Gnd, \\ V_{CC} = 3.6 V \end{array}$			125	μA	1, 2, 3	
I <sub>OZ</sub>	TRI-STATE Output Leakage Current	$V_0 = V_{CC}$ or Gnd, Enable = Vil, $V_{CC}$ = 3.6V, Enable = $V_{IH}$			±20	μΑ	1, 2, 3	
I <sub>SC</sub>	Output Short Circuit Current	$V_{I} = V_{CC} \text{ or Gnd},$ $V_{CC} = 3.0/3.6V, V_{O} = 0.0V$	(2), (3)	-30	-160	mA	1, 2, 3	
I <sub>Off</sub>	Output Leakage Current "Power	$V_{CC} = 0V, V_{O} = 6.0V \text{ or } 3.0V$			100	μA	1, 2, 3	
	Off"	$V_{CC} = 0V, V_{O} = -0.25V$			-200	μA	1, 2, 3	

(1)Parameter tested Go-No-Go only.

See EIA specification RS-422 for exact test condition. (2)

(3) This is a current sourced when a high output is shorted to Gnd. Only one output at a time should be shorted.

### DS26LV31M Electrical Characteristics AC Parameters - Propagation Delay Time

The following conditions apply to all the following parameters, unless otherwise specified. AC:  $V_{CC} = 3.0/3.6V$ 

	Parameter	Test Conditions	Notes Min M		Max	Units	Sub- groups
t <sub>PLHD</sub>	Differential Propagation Delay (Low to High)	$R_L = 100\Omega, C_L = 50pF$	(1)	5.0	25	ns	9, 10, 11
t <sub>PHLD</sub>	Differential Propagation Delay (High to Low)	$R_L = 100\Omega, C_L = 50pF$	(1)	5.0	25	ns	9, 10, 11
t <sub>SKD</sub>	Differential Skew t <sub>PHLD</sub> -t <sub>PLHD</sub> (same channel)	$R_L = 100\Omega, C_L = 50pF$	(1)		5.0	ns	9, 10, 11
t <sub>SK1</sub>	Pin to Pin Skew (same device)	$R_{L} = 100\Omega, C_{L} = 50pF$	(1)		5.0	ns	9, 10, 11
t <sub>PZH</sub>	Output Enable Time	$R_L = 110\Omega$ to Gnd, $C_L = 50pF$	(2)		40	ns	9, 10, 11
t <sub>PZL</sub>	Output Enable Time	$R_L = 110\Omega$ to $V_{CC}$ , $C_L = 50 pF$	(2)		40	ns	9, 10, 11
t <sub>PHZ</sub>	Output Disable Time	$R_L = 110\Omega$ to Gnd, $C_L = 50pF$	(2)		35	ns	9, 10, 11
t <sub>PLZ</sub>	Output Disable Time	$R_L$ = 110 $\Omega$ to $V_{CC},C_L$ = 50pF	(2)		35	ns	9, 10, 11

Generator waveform is specified as follows: f = 1MHz, Duty Cycle = 50%,  $Z_O = 50\Omega$ ,  $t_R = t_F \le 6$ nS. Driver input = 0V to 3V with measure points equal to 1.5V. Differential output  $V_{\text{Diff}} = D_O - \overline{D}^O$  with measure point equal to 0V. Generator waveform is specified as follows: f = 1MHz, Duty Cycle = 50%,  $Z_O = 50\Omega$ ,  $t_R = t_F \le 6$ nS. En/En inputs = 0V to 3V with measure points equal to 1.5V on the inputs, to 1.3V on the outputs for  $Z_L$  and  $Z_H$ , and ( $V_{OL} + 0.3V$ ) for  $L_Z$ , and ( $V_{OH}$ - 0.3V) for  $H_Z$ . (1)

(2)

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## **REVISION HISTORY**

Released	Revision	Section	Originator	Changes
3/01/06	*	New Release, Corporate format	L. Lytle	1 MDS data sheets converted into one Corp. data sheet format. MNDS26LV31-X Rev 1A0 will be archived.
4/15/2013	A		TIS	Changed layout of National Data Sheet to TI format

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## **PACKAGING INFORMATION**

Orderable Device	Status	Package Type				Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
5962-9858401QFA	ACTIVE	CFP	NAD	16	19	TBD	Call TI	Call TI	-55 to 125	DS26LV31W- QML Q 5962-98584 01QFA ACO 01QFA >T	Samples
DS26LV31W-QML	ACTIVE	CFP	NAD	16	19	TBD	Call TI	Call TI	-55 to 125	DS26LV31W- QML Q 5962-98584 01QFA ACO 01QFA >T	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

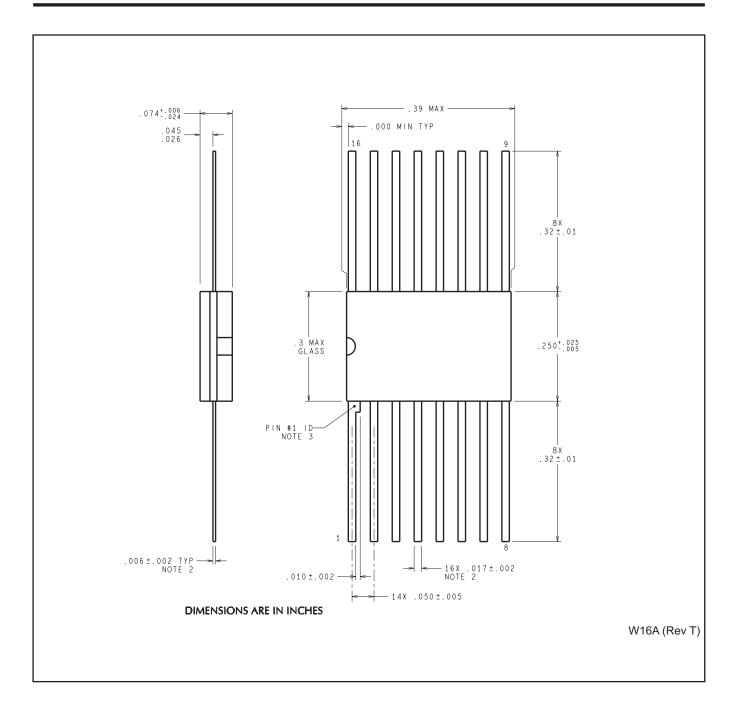
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15-Apr-2013

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